



RFM100-500-100-HSD

100-500MHz 100W Class A/AB High Performance Amplifier with High Speed Disable

- ❖ Class A/AB 100W linear amplifier
- ❖ Fast output disable, $\leq 1\mu\text{sec}$
- ❖ VVA with over 30dB range
- ❖ Analog temperature out
- ❖ High temperature alarm
- ❖ Independent MMIC disable
- ❖ Temperature compensated bias
- ❖ Available with input limiter and/or heatsink and fan



The RFM100-500-100-HSD is a Class A/AB high performance amplifier module, excellent as a driver stage in military communication or radar systems. It features fast output disable with $\leq 1\mu\text{sec}$ response time. An independent MMIC disable line and VVA afford additional quieting of the RF chain. It utilizes conservatively rated LDMOS transistors for optimum performance and maximum reliability.

Specifications				
$V_{\text{supply}} = +28\text{VDC}$, $I_{\text{DQ}} = 1.45\text{A}$, $P_{\text{out}} = 100\text{W}$, $T_{\text{base}} = 40^\circ\text{C}$, $Z_{\text{load}} = 50\Omega$				
Parameter	Min	Typ	Max	Units
Freq. Range	100		500	MHz
$P_{1\text{dB}}$	90	105		W
Input Power		-3	0	dBm
Gain	50	53		dB
Gain Flatness		+/-0.9	+/-1.5	dB
Drain Current		6.7	7.6	A
Efficiency	47	53		%
IRL		-22	-14	dB
f_2		-41	-24	dBc
f_3		-21	-10	dBc
IMD_3 100W PEP, $\Delta f = 10\text{kHz}$. See Fig. 2 for 50W PEP.		-31	-24	dBc
Dimensions	3.60 X 6.55 X 1.30 (91.44 X 166.37 X 33.02)			inch (mm)

Maximum Ratings	
Operation beyond these ratings may damage amplifier.	
Parameter	Value
V_{supply}	24-30VDC
Bias Current	2.0A
Drain Current	9.0A
Load Mismatch*	5:1 (28VDC) 3:1 (30VDC)
Housing Base Temperature	65°C
Storage Temperature	-40°C to 85°C

*All phase angles, 100W forward power, current limited to 9.0A @ 28VDC, 8.4A @ 30VDC.

Option Ordering Info	
Input limiter	RFM100-500-100-HSD-LIM
Heatsink and fan	RFM100-500-100-HSD-HSF

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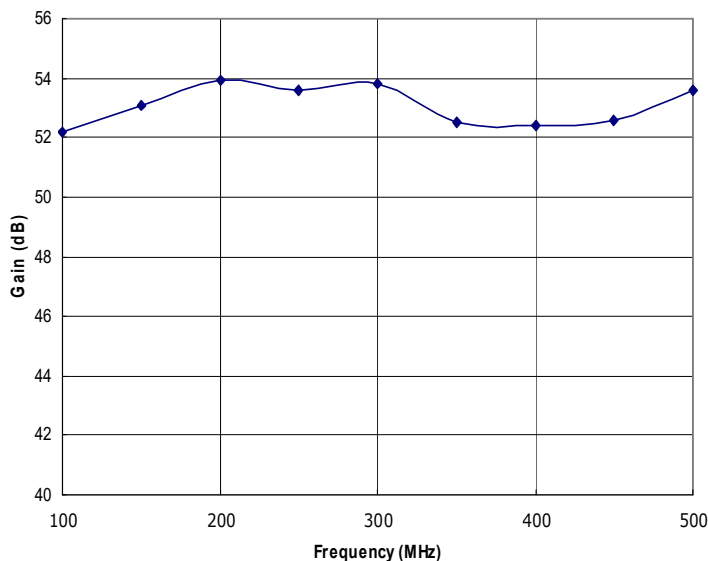


Figure 1: RFM100-500-100-HSD Typical Gain @ $P_{out}=100W$.

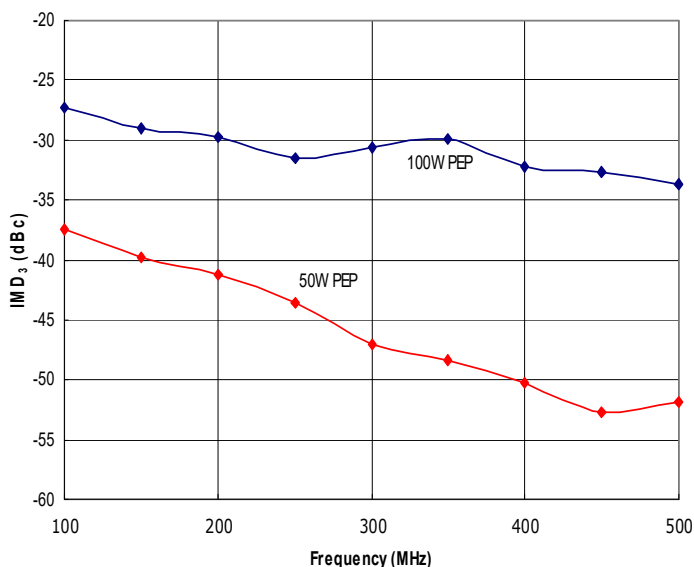


Figure 2: RFM100-500-100-HSD Typical IMD_3 @ 100W and 50W PEP, $\Delta f=10kHz$. For improved linearity, see our RFM100-500-50-HSD Class A amplifier.

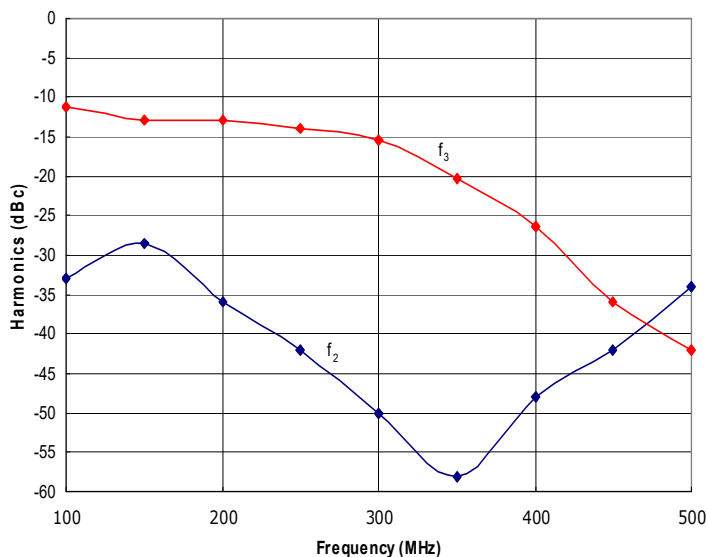


Figure 3: RFM100-500-100-HSD Typical f_2 and f_3 @ $P_{out}=100W$.

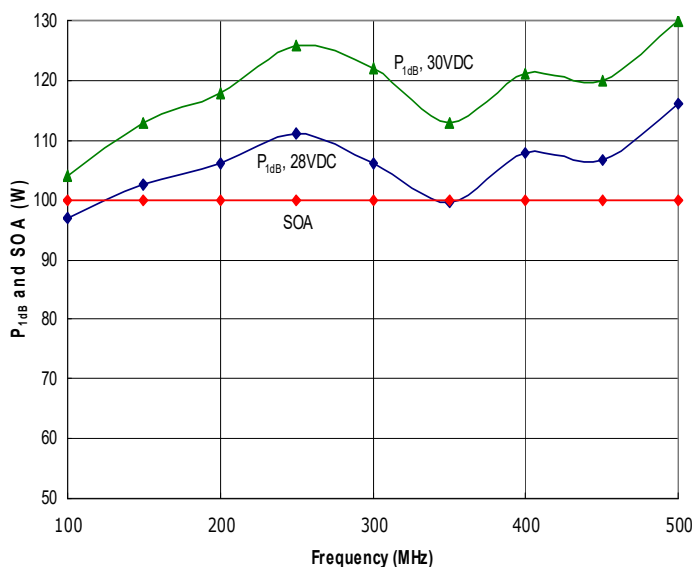


Figure 4: RFM100-500-100-HSD Typical P_{1dB} and Safe Operating Area (SOA). Do not exceed the SOA shown above without first contacting RFMPT to discuss your application.

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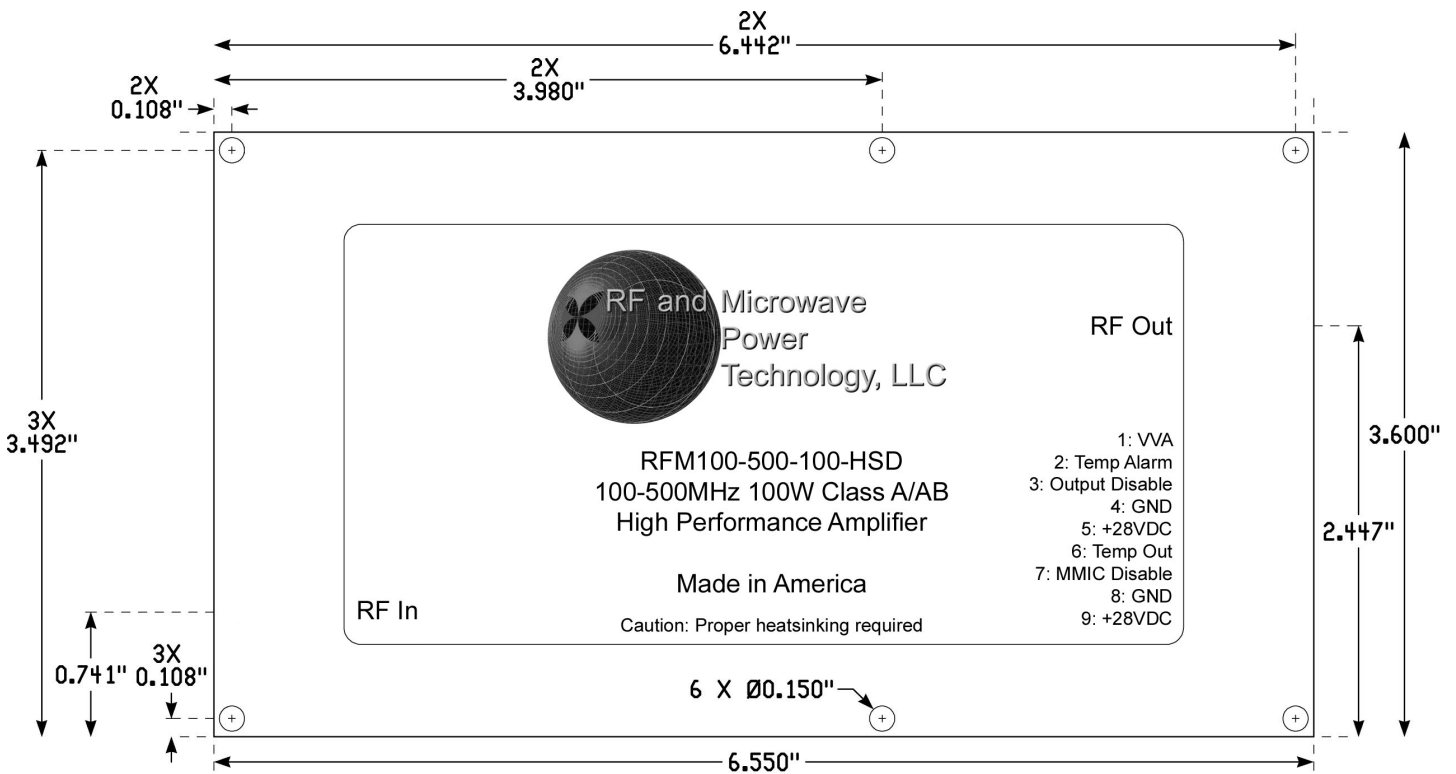




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Amplifier Mounting Hole and RF Locations



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Interface Pins and Functions

- 1: VVA** The voltage variable attenuator has a slope of approximately 30dB/volt, from 0.65 to 1.65V. Maximum attenuation is reached by 2.0V. The acceptable control range is 0 to 3.6V. Do not exceed 3.6VDC on this pin. The maximum RF input power is 0dBm, without the limiter option. Do not exceed the SOA in Figure 4, with or without the limiter option. **The VVA control voltage should be set to zero volts during amplifier power up and power down.**
- 2: Temp Alarm** This indicates an over-temp condition, and is set to trip at a housing base temperature of approximately +65°C. It is an open drain output, pulled up internally to +15VDC, and will pull down to 0V at +65°C. The end user may either scale this range to suitable voltages with a simple resistive divider, or use an analog or digital input capable of handling +15VDC. This signal exhibits 5°C of hysteresis, and will reset to +15VDC at approximately +60°C.
- 3: Output Disable** This is active high at +5VDC. It disables the second and output stages of the amplifier, and will reduce full rated output power to zero in $\leq 1\mu\text{sec}$. When set to 0VDC, the amplifier will return to full power in approximately 50 μsec .
- 4: GND** Amplifier ground. Connect to power supply return/ground. Use in parallel with pin #8. A minimum of 20 gauge wire is recommended.
- 5: +28VDC** The nominal supply voltage is +28VDC. As low as +24VDC may be used, with a reduction in $P_{1\text{dB}}$, harmonics, and IMD performance. Up to +30VDC may be used with a reduction in maximum VSWR withstand. See page 1. Use in parallel with pin #9. A minimum of 20 gauge wire is recommended.
- 6: Temp Out** This is an analog signal that is a nominal +0.75V at +25°C. It has a positive slope of 10mV/°C with increasing temperature. An offset will exist between the temperature reported on this pin and the actual housing base temperature directly under the output transistor, until steady state conditions are reached. It is up to the end user to properly characterize this signal's response with their chosen cooling configuration.
- 7: MMIC Disable** This is a supplementary disable pin, for additional amplifier quieting at the user's discretion.
- 8: GND** Amplifier ground. Connect to power supply return/ground. Use in parallel with pin #4. A minimum of 20 gauge wire is recommended.
- 9: +28VDC** The nominal supply voltage is +28VDC. As low as +24VDC may be used, with a reduction in $P_{1\text{dB}}$, harmonics, and IMD performance. Up to +30VDC may be used with a reduction in maximum VSWR withstand. See page 1. Use in parallel with pin #9. A minimum of 20 gauge wire is recommended.

Limiter Option

The limiter option significantly impacts amplifier linearity. Please contact RFMPT to learn more.

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Instructions for Amplifier Use

- 1) If not supplied with a heatsink, apply a layer of high performance thermal grease (Wakefield Type 122 or equivalent) to the underside of the amplifier housing. Thinner is better, but ensure that when mounted to your heatsink, contact across the *entire* module base is made. Gaps and air bubbles will significantly reduce cooling, leading to possible amplifier damage. Use six #6-32 screws to mount the amplifier to your heatsink.
- 2) Guarantee sufficient airflow through the heatsink fins to keep the maximum housing base temperature at or less than that specified in the Maximum Ratings section. Contact RFMPT for details on how to qualify your heatsink's performance, if needed.
- 3) Connect a proper signal source to the RF IN connector, and desired load to the RF OUT connector. Torque connectors to industry standards for the type supplied with the amplifier.
- 4) Connect DC V_{supply} to pins 5 and 9 of the interface connector. Connect power supply return/ground to pins 4 and 8 of the interface connector. Ensure that V_{supply} is within the voltage range in the Maximum Ratings section.
- 5) Apply desired signals/monitoring lines to remainder of interface pins. Refer to the Interface Pins and Functions section for signal descriptions, limits, and timing requirements.
- 6) Apply DC power then sufficient RF drive to achieve desired output level. Ensure that the Safe Operating Area (SOA) power level indicated in Figure 4 is not exceeded, or amplifier damage may occur, and will void the warranty.
- 7) To disconnect the amplifier, first remove the RF drive, then DC power, then the RF connections.

Contact the factory at sales@rfmpt.com with any questions, or for special options, testing requirements, and/or operating conditions not specified in this document.

Document Control

Revision	Date	Notes
A	8-11-2016	Initial release.
B	2-2-2025	Updated specifications for all LDMOS design.

